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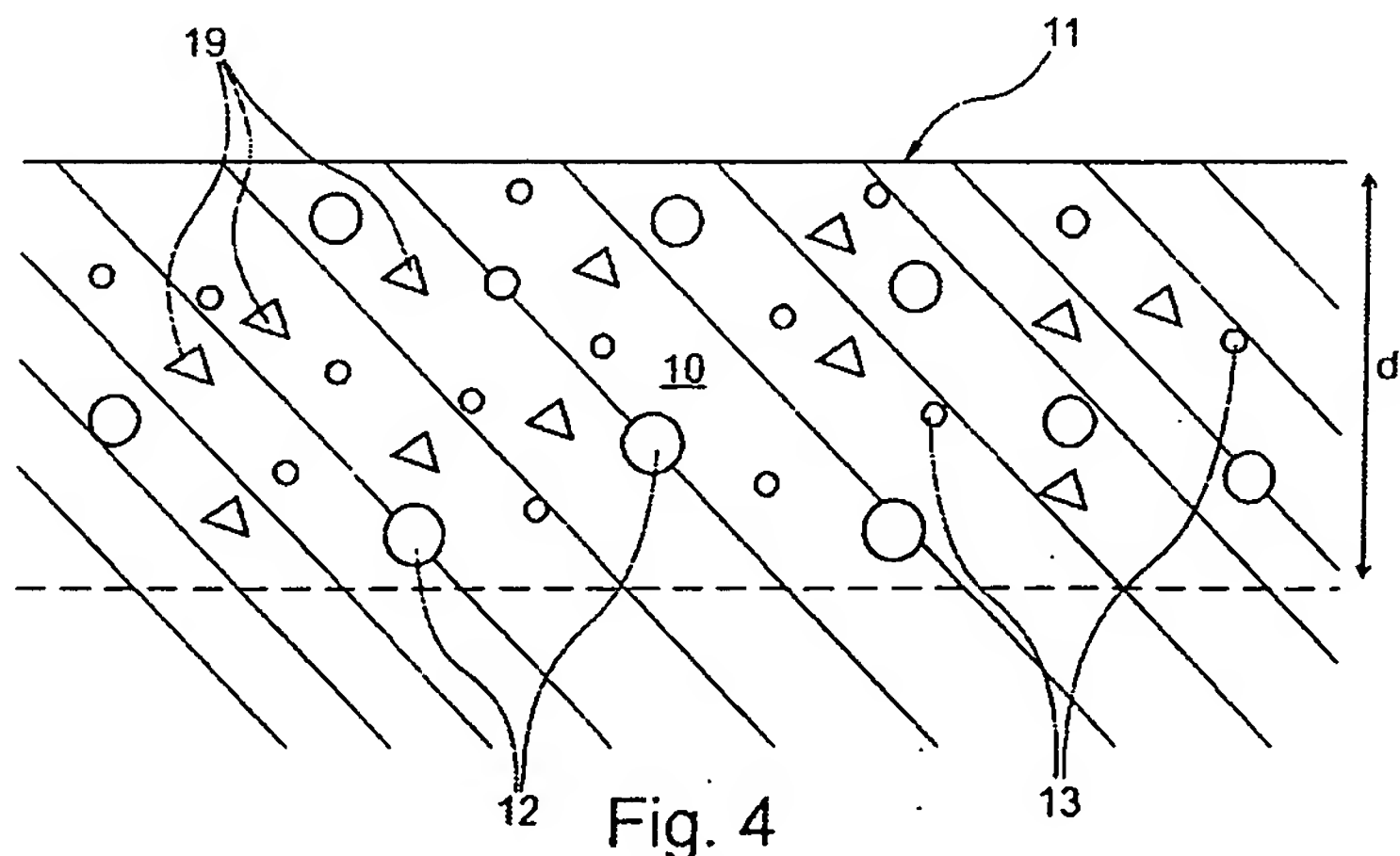


Fig. 4

(57) Abstract: A method for the antimicrobial provision of implant surfaces with silver, in which the method comprises an anodizing of the implant surface with an electrolyte, in which the electrolyte has a silver-yielding substance.

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Antimicrobial provision of titanium and titanium alloys with silver

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15 **Subject of the present invention**

The present invention relates to a method for the antimicrobial provision of titanium and titanium alloys with silver, in particular a method which permits an antimicrobial provision of titanium and titanium alloys with silver which makes possible a  
20 controlled release of silver ions over a particular period of time.

**Background of the invention**

Numerous methods are known for the surface treatment of titanium, for instance  
25 Type I-V anodizing, electropolishing, plasma nitriding etc. Likewise, numerous methods are known for the antimicrobial provision of surfaces with silver, for instance deposition from the vapour phase (PVD), from oversaturated solution, or by ion implantation.

30 In addition, a coating of silver on titanium is known from "Antimicrobial titanium/silver PVD coatings on titanium" by Andrea Ewald et al., published on 24th March 2006 in BioMedical Engineering OnLine2006, 5:22 doi:10.1186/1475-925X-5-22.

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### Summary of the invention

The object of the invention is to provide the method which permits an improved antimicrobial provision of titanium and titanium alloys with silver, which makes  
5 possible a controlled release of silver ions over a particular period of time.

The object of the invention is solved by the subject matter of the independent claims, with advantageous developments thereof being embodied in the dependent claims.

10 According to an example embodiment of the invention, a method is made available for the antimicrobial provision of implant surfaces with silver, the method comprising an anodizing of the implant surface in the presence of an electrolyte, the electrolyte comprising a silver-yielding substance.

15 Thereby, a simultaneous establishing of a silver deposit and a surface treatment, for instance for hardening and for increasing the wear resistance, is provided.

According to an example embodiment of the invention, the silver-yielding substance comprises a silver salt.

20

Thereby, a high number of silver ions can be easily provided in an electrolyte.

According to an example embodiment of the invention, the silver salt comprises silver nitrate.

25

Silver nitrate is soluble relatively easily in water, so that an aqueous solution can be used as electrolyte.

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According to an example embodiment of the invention, the silver is at least partially reduced from silver ions by a reducing agent.

5 A reducing agent is able to make available for the silver ions the electrons which are missing for a required reduction. The reducing agent can also be an electron source acting from the exterior.

According to an example embodiment of the invention, the electrolyte comprises the reducing agent.

10

In this way, the reducing agent can be provided directly in the electrolyte.

According to an example embodiment of the invention, the reducing agent comprises sodium borohydride.

15

Sodium borohydride is a particularly suitable reducing agent, in particular for silver ions in an aqueous solution.

20 According to an example embodiment of the invention, the anodizing comprises an anodizing of Type II.

In this way, a hardening and an introduction of silver into relatively great depths of for example 5 to 10 micrometres can be achieved.

25 According to an example embodiment of the invention, the anodizing comprises an anodizing of Type III.

In this way, a depositing of a defined layer can take place on the implant surface, without substantially affecting the base substance of the implant.

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According to an example embodiment of the invention a solution is added to the electrolyte during anodizing which has a concentration of  $1 \times 10^{-4}$  M to  $1 \times 10^{-2}$  M, preferably approximately  $1 \times 10^{-3}$  M silver nitrate and a concentration of  
5  $2 \times 10^{-4}$  M to  $2 \times 10^{-2}$  M, preferably approximately  $2 \times 10^{-3}$  M sodium borohydride.

These concentrations have proved to be particularly advantageous for the application process.

10

According to an example embodiment of the invention, the silver ions are reduced and are incorporated into the anodizing layer of the implant surface or an oxide layer situated thereon before a precipitation as nanoparticles.

15 In this way, the silver components can become integral components of the base material or of the coating.

According to an example embodiment of the invention, a method for the antimicrobial provision of implant surfaces with silver comprises a silver  
20 implantation.

By a silver implantation, silver can be introduced for example by a sputtering process into the uppermost layers of an implant surface.

25 According to an example embodiment of the invention, the method further comprises an anodizing of the implant surface.

In this way, the implant surface can be surface-treated after a silver implantation, for instance hardened or made more wear-resistant against wear of soft or hard tissue.

- 5 -

According to an example embodiment of the invention, parameters of a silver implantation are selected so that a penetration depth of the silver lies between 0.5 and 2 micrometres, in particular 1 micrometre.

5

In this way, a defined delivery of silver can be achieved over a particular period of time.

According to an example embodiment of the invention, a method for the antimicrobial provision of implant surfaces with silver comprises a physical gas phase deposition.

10

In this way, a defined coating can be applied onto the surface of an implant.

According to an example embodiment of the invention, the method further comprises an anodizing of the implant surface.

15

In this way, the implant surface can be surface-treated after a silver implantation, for instance hardened or made more wear-resistant against wear of soft or hard tissue.

20

According to an example embodiment of the invention, the physical gas phase deposition is carried out alternately with silver and with titanium.

In this way, not only a silver implantation, but a silver-titanium covering layer can be applied onto the base material, and namely by the alternating in defined layer thicknesses or a matrix for the chronologically controlled delivery of silver.

25

According to an example embodiment of the invention, the physical gas phase deposition is carried out simultaneously with silver and with titanium.

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In this way, not only a silver implantation but also a silver-titanium covering layer can be applied onto the base material, in which through the simultaneous application a faster coating can be achieved by simultaneous coating.

5

According to an example embodiment of the invention, the covering layer applied by physical gas phase deposition has a thickness between 1 and 3 micrometres, in particular 1 micrometre.

10 In this way, a particularly resistant coating can be applied.

According to an example embodiment of the invention, the anodizing comprises an anodizing of Type II or of Type III.

15 In this way, a hardening and an introduction of silver can be achieved into relatively great depths of for example 5 to 10 micrometres (Type II), or a deposition of a defined layer on the implant surface can take place, without substantially affecting the base substance of the implant (Type III).

20 According to an example embodiment of the invention, a computer program is provided which, when it is executed through a processor, is designed to carry out the method according to the invention.

According to an example embodiment of the invention, a computer-readable medium  
25 is provided, on which the computer program according to the invention is stored.

Through an anodizing, in particular of Type II and III, and the combined silver deposition it is made possible that silver or silver atoms are incorporated into the anodizing layer and thus become a component of the base material. The aim here is



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to fundamentally increase the Ag layer adhesion and to make possible a controlled release of the silver ions over a period of at least 10 days. In addition, the advantages of the anodizing can be combined with those of the silver doping/alloying such that the release of silver ions in the living tissue takes place in a controlled manner and a concentration is reached which is sufficiently high to achieve an antimicrobial effect for, for example, at least 10 days, which is in addition low enough not to act cytotoxically on the surrounding tissue. Typical values for the release of silver ions after 24h in buffered Ringer's solution lie between 0.5ppb and 50ppb, depending on the pre-treatment of the surface.

10

The individual features can of course also be combined with each other, whereby in part also advantageous effects can occur which go beyond the sum of the individual effects.

15 These and other aspects of the present invention are explained and clarified by reference to the example embodiments described hereafter.

#### **Brief description of the drawings**

20 Example embodiments are described below with reference to the following drawings.

Fig. 1 shows a layer structure according to a Type II anodizing.

Fig. 2 shows a layer structure according to a Type III anodizing.

25

Fig. 3 shows a layer structure with embedded silver according to a Type II anodizing.

Fig. 4 shows a layer structure with embedded silver according to a Type III anodizing.



Fig. 5 to Fig. 10 show surface structures which are able to be produced by methods according to example embodiments of the invention.

- 5 Fig. 11 to Fig. 13 show diagrammatic sequences of methods according to example embodiments of the invention.

#### Detailed description of example embodiments

- 10 The antimicrobial effect of silver ions or -salts can be achieved for example by stable silver nanoparticles. Thereby, an antimicrobial activity of silver nanoparticles can be achieved, which inhibits growth in the case of various bacteria. Silver nanoparticles of various concentrations can be used for this. As a result, various bacteria can already be suppressed at low concentrations of silver nanoparticles. The
- 15 effect of a generation of free radicals is responsible for this in the case of silver nanoparticles for an inhibiting of microbial growth. Silver nanoparticles can be used as effective growth inhibitors for various microorganisms, whereby they can be used for various medical apparatus and antimicrobial control systems.
- 20 An anodizing of Type II and III are methods of anodizing titanium which are relevant for medical technology. The aim here is to stabilize the natural oxide layers (e.g. rutile), which are unsuitable per se, so that a minimal Ti wear occurs in contact with soft or hard tissue. Through Type II, in addition, the fatigue strength is increased by approximately 15-30%.
- 25 In Type II anodizing, a basic electrolyte is used. The first step of a Type II anodizing is an electrolytic treatment in a basic bath. A voltage is applied between the material and the bath. This causes the surface material to be melted point by point over the entire surface 11. This procedure removes the original oxide layer and brings about

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an oxygen- and silicon diffusion 12 up to a depth d1 into the material 10. This depth can be for example 5 to 10 micrometres. The material 10 can be titanium or a titanium alloy. Likewise, an oxidizing of the titanium can take place as  $\text{TiO}_x$  13. In addition, a new porous oxide layer is grown on the surface 11. In a second step, this  
5 porous oxide layer is removed by blasting with glass spherules. The resulting surface structure is shown in Fig. 2.

The diffused oxygen forms partially oxides 13, which have a very great hardness. Oxygen 12 and oxides 13 are embedded into the material interstitially or forming  
10 intermediate spaces, forming an integral part of the material 10. The region of a diffusion is named conversion layer d1.

In Type III an acid electrolyte is used. In a first step, the original oxide layer is removed in an acid bath. The electrolytic process follows in a second step. A voltage  
15 is again applied in an acid bath between the material and the bath. The voltage is used to control the thickness d2 of a new titanium dioxide 13  $\text{TiO}_2$  oxide layer on the surface 11. This thickness d2 can be for example 0.02 to 0.2 micrometres. The parts are hereafter not blasted with glass spherules, because this would destroy the oxide layer of a defined thickness d2. The resulting surface structure is shown in Fig. 2.

20

The surface 14 of anodized Type III shows a similar structure to a non-anodized surface. The main difference is the thickness of the oxide layer d2, which is smaller than the thickness d1 by more than one order of magnitude. The transparency and defined thickness d2 of a layer makes possible a colouring of the surface. The colour  
25 is produced by a light interference which originates from incident external light 21, 23, which is partially reflected 22 by the surface layer 14, and is partially reflected 24 by the material surface 11. The colour depends here on the layer thickness which can be controlled by the anodizing process.

- 10 -

In the separating of silver from the oversaturated solution, an aqueous solution of for example  $1 \times 10^{-3}$  M silver nitrate is mixed in the proportion approximately 1:3 with an aqueous solution of  $2 \times 10^{-3}$  M sodium borohydride as reducing agent. On the mixing of the two solutions, the Ag ions are reduced and precipitated as nanoparticles in the solution and are stabilized by stirring. The 3.3nM solution can then be diluted to the desired concentration.

According to an embodiment of the invention, a solution of a silver salt and of a reducing agent is added to the electrolyte during anodizing. On mixing of the solution with the electrolyte, the Ag ions can now be reduced and still incorporated into the sample surface or the oxide layer before precipitating as nanoparticles. The reducing can take place by any desired suitable means.

The result can be seen in Fig. 3 and Fig. 4. These two illustrations correspond substantially to Fig. 1 and Fig. 2, but with the difference that in the structure shown in Fig. 3 and Fig. 4 an embedding of silver 19 has taken place. Through the presence of reduced silver in the electrolyte, silver 19 penetrates up to a depth of approximately  $d_1$  on the anodizing of Type II (Fig. 4). In addition, silver 19 precipitates together with the titanium dioxide 13 and leads to a layer thickness of  $d_2$  (Fig. 3) on the otherwise substantially unchanged base material 10.

In particular, according to an embodiment of the invention, on anodizing of Type II/III, a solution of  $1 \times 10^{-3}$  M silver nitrate and of  $2 \times 10^{-3}$  M sodium borohydride can be added to the electrolyte. On mixing the two solutions with the electrolyte, the Ag ions can now again be reduced here and still incorporated into the sample surface 11 (Fig. 2, Fig. 4) or the oxide layer (Fig. 1, Fig. 3) before the precipitation as nanoparticles 19. The reducing takes place here by the reducing agent sodium borohydride, likewise dissolved in the electrolyte.

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It is noted that instead of silver nitrate, other suitable silver salts can also be used. The required silver ions can also be produced intrinsically. In addition, the use is not restricted to the use of sodium borohydride. Instead of this, other suitable reducing agents can also be used. Alternatively, suitable agents, acting as catalyst, can also be  
5 used in order to achieve a precipitation or deposition of silver.

Alternatively, a provision of a titanium or titanium alloy surface with silver can also take place by means of an Ag ion implantation or a PVD coating.

10 An Ag ion implantation is carried out in a vacuum chamber at low pressures of  $10 \times 10^{-4}$  mbar. The metal ions are accelerated after production onto the titanium surface and penetrate into the latter up to a depth of one to two micrometres.

This process is now carried out alternately with Ag and with Ti atoms, in order to  
15 apply not only an Ag implantation but an Ag-Ti covering layer onto the base material.

The term physical gas phase deposition (Physical Vapour Deposition, abbreviated to PVD) designates a group of vacuum-based coating methods or thin layer  
20 technologies, in which the layer is formed directly by condensation of a material vapour of the starting material. The material which is to be deposited is generally present in solid form in the generally evacuated coating chamber. The material, which is designated as the target, is vaporized by bombardment with laser beams, magnetically deflected ions or electrons and by arc discharge. The extent of the  
25 proportion of atoms, ions or larger clusters in the vapour is different from method to method. The vaporized material moves either ballistically or guided through electric fields through the chamber and in so doing impinges onto the parts which are to be coated, where the layer formation occurs. So that the vapour particles also reach the components and are not lost by scattering on the gas particles, operations must be

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carried out in vacuum. Typical operating pressures lie in the range of  $10^{-4}$  Pa to approximately 10 Pa. As the vapour particles spread in a straight line, areas which are not visible from the site of the vapour source are coated at a lower coating rate. If all areas are to be coated as homogeneously as possible, the parts must be moved in a  
5 suitable manner during coating. This takes place generally by rotation of the substrate. When the vapour particles now impinge onto the substrate, they begin to deposit themselves on the surface by condensation. The particles do not remain here at the original location at which they impinge onto the substrate, but rather move, depending on how high their energy is, along the surface (surface diffusion), in order  
10 to find an energetically more favourable place. These are sites on the crystal surface with as many neighbours as possible (higher binding energy).

A process of a PVD coating can be carried out in commercially available PVD systems. Here, a PVD covering layer of for example approximately 2 micrometres  
15 consisting of Ti and Ag atoms is applied simultaneously onto the Ti base material. For this PVD coating on titanium, for example the coating can be carried out for example with a thickness for example of approximately two micrometres on the titanium surface by simultaneous vaporization of two materials, for example titanium and silver, in an inert argon atmosphere. Here, two precursors can then be used at the  
20 same time. Silver contents of 0-100% can be realized here in the covering layer.

An ion implantation is a possibility for the modifying of surface characteristics of materials. It is similar to a coating process, but it does not cause any build-up of a layer onto the surface. Originally developed for use in semiconductor applications,  
25 an ion implantation uses a high energy ion beam of e.g. positively charged atoms for modifying a surface structure and a surface chemistry of materials at low temperatures. Here, however, the process does not bring about any disadvantageous effects in the component dimensioning or in material characteristics. Several surface characteristics can be improved by an ion implantation, including the hardness or

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resistance to wear or chemical stress or of the friction coefficient. The process can be applied to almost any material, including most metals, likewise on ceramics and polymers. However, the effects of the process are typically material-specific. In particular, components treated with ion implantation can be prostheses or implants of titanium, which can be made harder and more able to support loads by the process of ion implantation. The process of an ion implantation is carried out in a vacuum chamber at very low pressures, with a large number of ions bombarding the surface and penetrating into the surface, then interacting with the atoms of the substrate directly under the surface. A typical depth of an ion penetration is a fraction of a micrometre. The interactions of the energetic ions with the material modify the surface and endow it with significantly different characteristics from the original material. Specific changes in characteristic depend on the choice of the treatment parameters of the ion bombardment, for example the ion species, the energy and the total number of ions applied onto the surface. An ion implantation offers numerous advantages for the treating of surfaces, a great advantage being in the possibility of a selective modification of the surface without having a disadvantageous effect on the material characteristics, because the process is carried out at low substrate temperatures. The process is, in addition, easily controllable and reproducible and can be tailored to the modification of different surfaces in a desired manner.

20

The advantages of anodizing can be combined with those of silver doping/alloying for the method according to the invention such that the release of Ag ions in the living tissue takes place in a controlled manner and a concentration can be reached which is sufficiently high to achieve an antimicrobial effect for for example at least 10 days, but on the other hand can be low enough not to act in a cytotoxic manner on the surrounding tissue. Typical values for the release of Ag ions after 24h in buffered Ringer's solution lie between 0.5ppb and 50ppb, depending on the pre-treatment of the surface.

25



Ti-Ag systems produced through an Ag ion implantation or through a PVD coating can be subsequently treated by an anodizing of Type II or Type III in a suitable manner. This can take place optionally.

- 5 Fig. 5 shows a material 10 coated by a PVD process with a layer thickness d4, a coating of Ti 18 and Ag 19 having been applied here. The layer thickness can be in the order of approximately a few micrometres, for instance two micrometres. However, a coating only of Ag 19 can also be applied. Fig. 6 shows the material 10 shown in Fig. 5, after a subsequent anodizing of Type II, analogous to Fig. 2. Fig. 7
- 10 shows the material 10 shown in Fig. 5 after an anodizing of Type III, analogous to Fig. 1. The thicknesses of the layers or depths d1 and d2 are analogous to Fig. 2 and Fig. 1.

- Fig. 8 shows a material 10 treated with an Ag implanting up to a penetration depth of
- 15 d3. The penetration depth can be in the order of approximately a few micrometres, for instance one micrometre. However, a coating only of Ag 19 can also be applied. Fig. 9 shows the material 10 shown in Fig. 8, after a subsequent anodizing of Type II, analogous to Fig. 2. Fig. 10 shows the material 10 shown in Fig. 8 after an anodizing of Type III, analogous to Fig. 1. The thicknesses of the layers or depths d1
- 20 and d2 are analogous to Fig. 2 and Fig. 1.

- Fig. 11 shows the diagrammatic sequence of a method according to an embodiment of the invention. In step S1a an anodizing of Type II is carried out, as described above. Here, in step S4 a mixing of the electrolyte with a silver salt or equivalent is
- 25 carried out, in order to perform a process which leads in step S5, as described above, to a build-up of the surface structure according to Fig. 4.

Fig. 12 shows the diagrammatic sequence of a method according to an embodiment of the invention. In step S1b an anodizing of Type III is carried out, as described



above. Here, in step S4 a mixing of the electrolyte with a silver salt or equivalent is carried out, in order to perform a process which leads in step S5, as described above, to a build-up of the surface structure according to Fig. 3.

- 5 Fig. 13 shows a collection of possible diagrammatic sequences of a method according to an embodiment of the invention. In step S2 an Ag implantation is carried out, as described above. In step S3 a PVD process is carried out, as described above. Following step S2 or step S3, in step S1a an anodizing of Type II is carried out, as described above, or in step S1b an anodizing of Type III is carried out, as  
10 described above, which respectively leads in step S5 to a coating. In the sequence of steps S2, S1a, S5, this leads, as described above, to a build-up of the surface structure according to Fig. 9. In the sequence of steps S2, S1b, S5, this leads, as described above, to a build-up of the surface structure according to Fig. 10. In the sequence of steps S3, S1a, S5, this leads, as described above, to a build-up of the surface structure  
15 according to Fig. 6. In the sequence of steps S3, S1b, S5, this leads, as described above, to a build-up of the surface structure according to Fig. 7.

It is noted that the term "comprise" does not rule out further elements or method steps, likewise the term "a" does not rule out several elements and steps.

20

The reference numbers which are used serve merely to increase the comprehensibility and are in no way regarded as restrictive, with the scope of protection of the invention being expressed by the Claims.

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### Patent Claims

1. A method for the antimicrobial provision of implant surfaces with silver, in which the method comprises:  
5 an anodizing of the implant surface in the presence of an electrolyte (S1a, S1b),  
in which the electrolyte comprises a silver-yielding substance (19).
2. The method according to Claim 1, in which the silver-yielding substance  
10 comprises a silver salt.
3. The method according to Claim 2, in which the silver salt comprises silver nitrate.
- 15 4. The method according to any of Claims 1 to 3, in which the silver is reduced at least partially from silver ions by a reducing agent.
5. The method according to Claim 4, in which the electrolyte comprises the reducing agent.  
20
6. The method according to Claim 5, in which the reducing agent comprises sodium borohydride.
7. The method according to any of the preceding claims, in which the anodizing  
25 comprises an anodizing of Type II (S1a).
8. The method according to any of the preceding claims, in which the anodizing comprises an anodizing of Type III (S1b).

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9. The method according to any of the preceding claims, in which on anodizing, a solution is added to the electrolyte which has a concentration of  $1 \times 10^{-4}$  M to  $1 \times 10^{-2}$  M, preferably approximately  $1 \times 10^{-3}$  M silver nitrate and a  
5 concentration of  $2 \times 10^{-4}$  M to  $2 \times 10^{-2}$  M, preferably approximately  $2 \times 10^{-3}$  M sodium borohydride.
10. The method according to any of the preceding claims, in which silver ions are reduced and are incorporated before precipitation as nanoparticles into the anodizing  
10 layer (d1) of the implant surface (11) or an oxide layer (d2) situated thereon.
11. A method for the antimicrobial provision of implant surfaces with silver, in which the method comprises:  
a silver implantation (S2).  
15
12. The method according to Claim 11, in which the method further comprises:  
an anodizing (S1a, S1b) of the implant surface.
13. The method according to Claim 11 or 12, in which parameters of a silver  
20 implantation are selected so that a penetration depth (d3) of the silver lies between 0.5 and 2 micrometres, in particular at approximately 1 micrometre.
14. A method for the antimicrobial provision of implant surfaces with silver, in which the method comprises:  
25 a physical gas phase deposition (S3).
15. The method according to Claim 14, in which the method further comprises:  
an anodizing (S1a, S1b) of the implant surface (11).

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16. The method according to Claim 14 or 15, in which the physical gas phase deposition is carried out alternately with silver (19) and with titanium (18).

17. The method according to any of Claims 14 to 16, in which the physical gas  
5 phase deposition is carried out simultaneously with silver (19) and with titanium  
(18).

18. The method according to any of Claims 14 to 17, in which the one covering  
layer applied by a physical gas phase deposition has a thickness (d4) between 1 and 3  
10 micrometres, in particular 1 micrometre.

19. The method according to any of Claims 11 to 18, in which the anodizing is an  
anodizing of Type II (S1a) or of Type III (S1b).

15 20. A computer program which, when it is executed by a processor, is designed  
to carry out the method according to any of Claims 1 to 19.

21. A computer-readable medium on which the computer program according to  
Claim 20 is stored.

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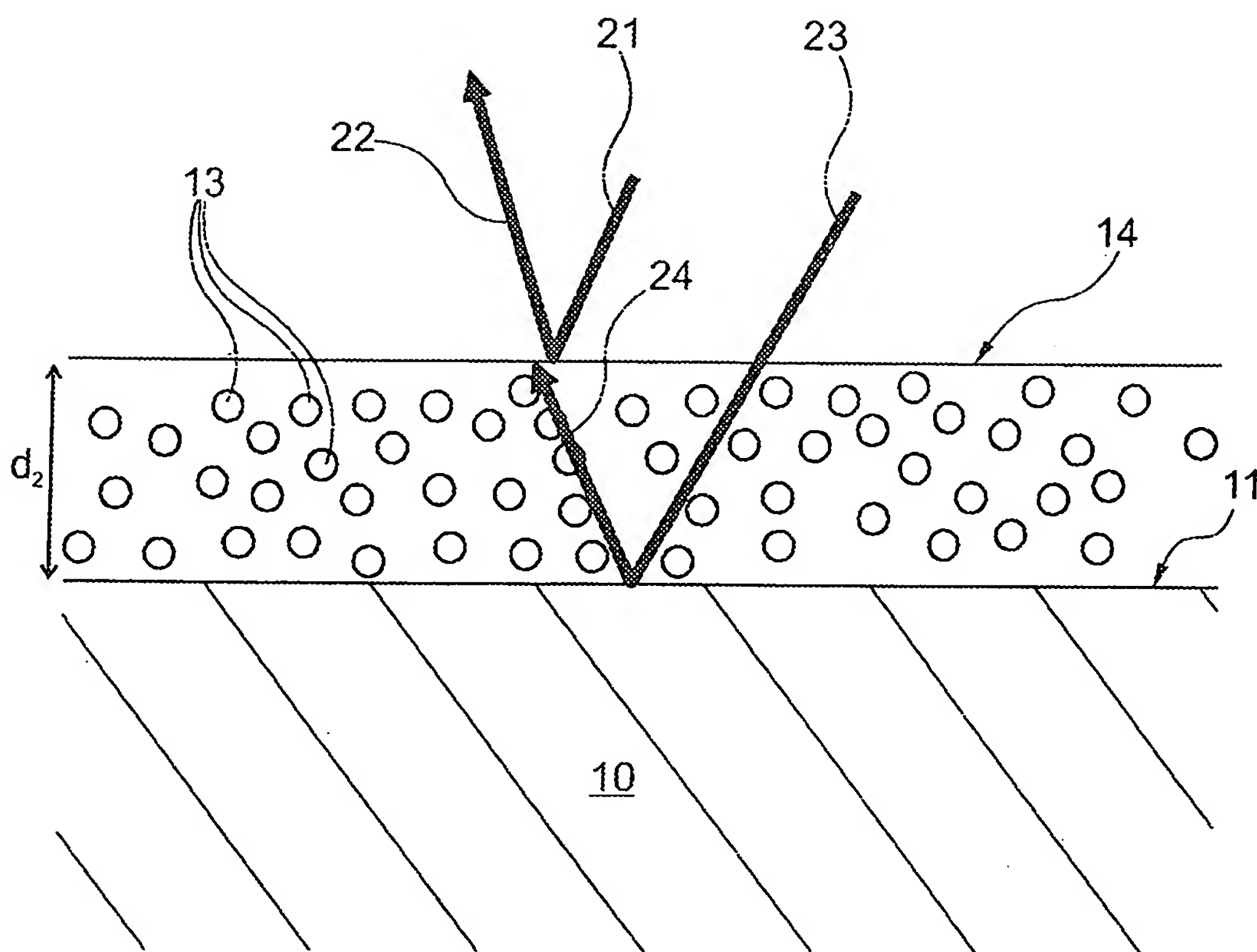


Fig. 1

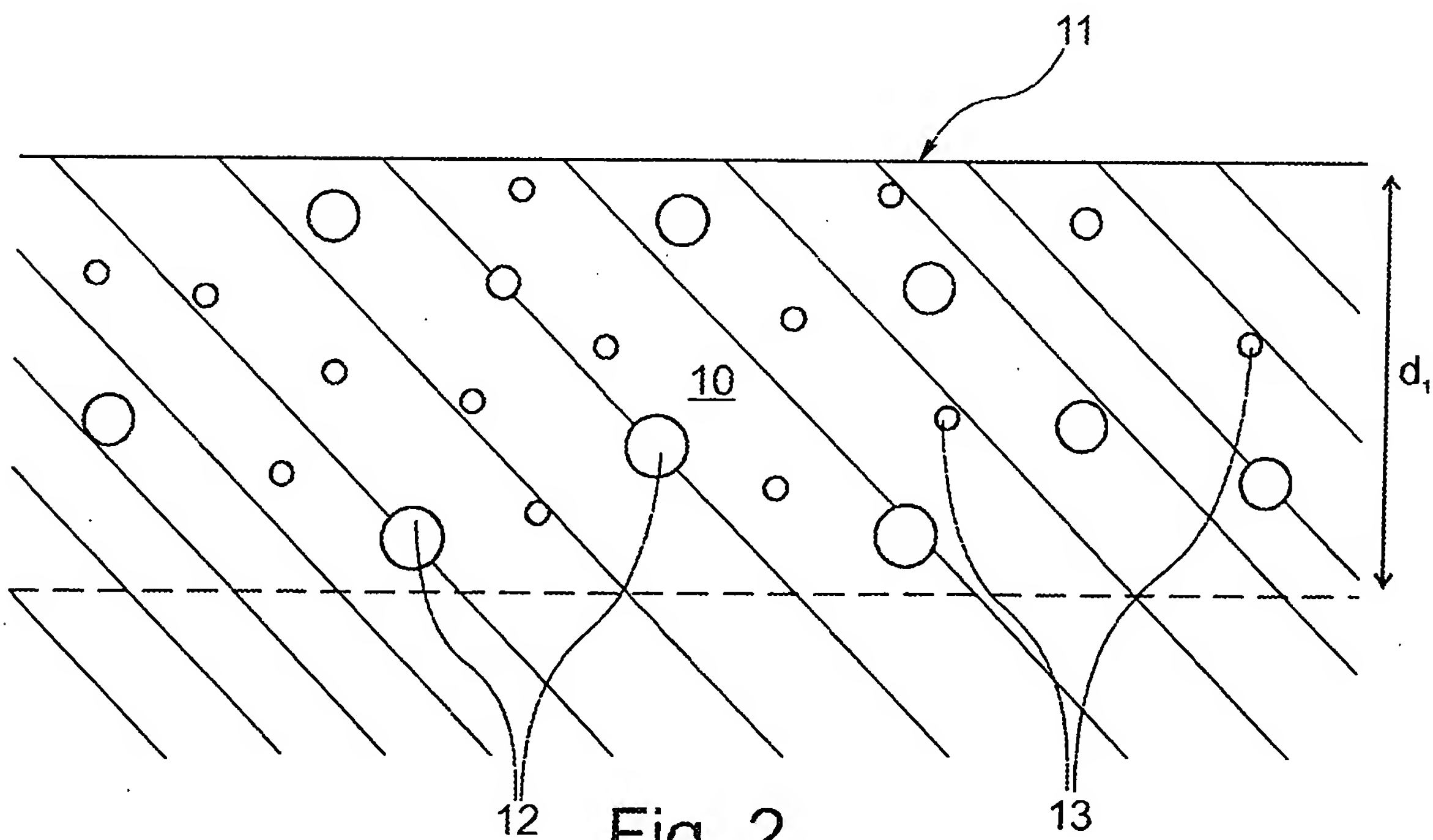


Fig. 2

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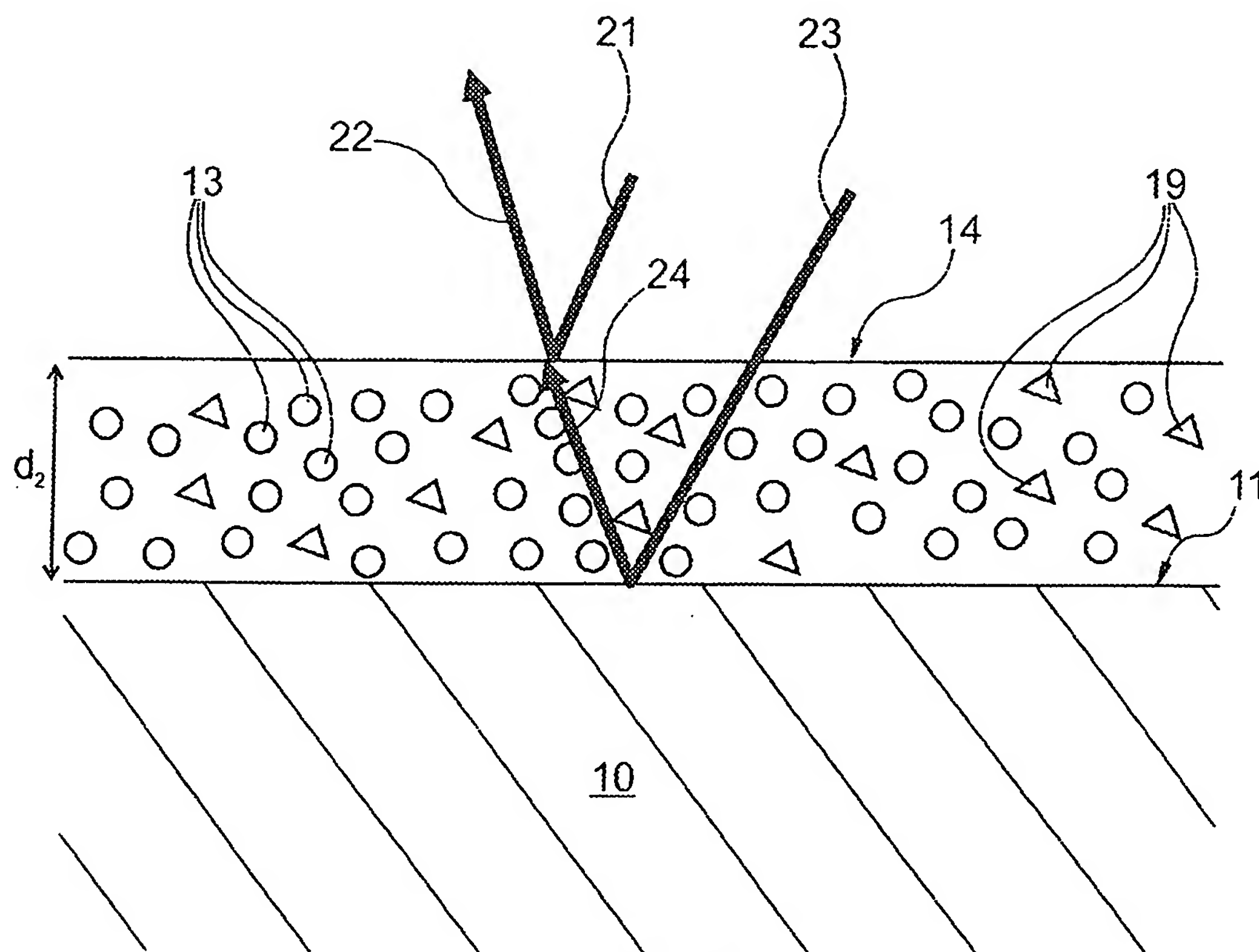


Fig. 3

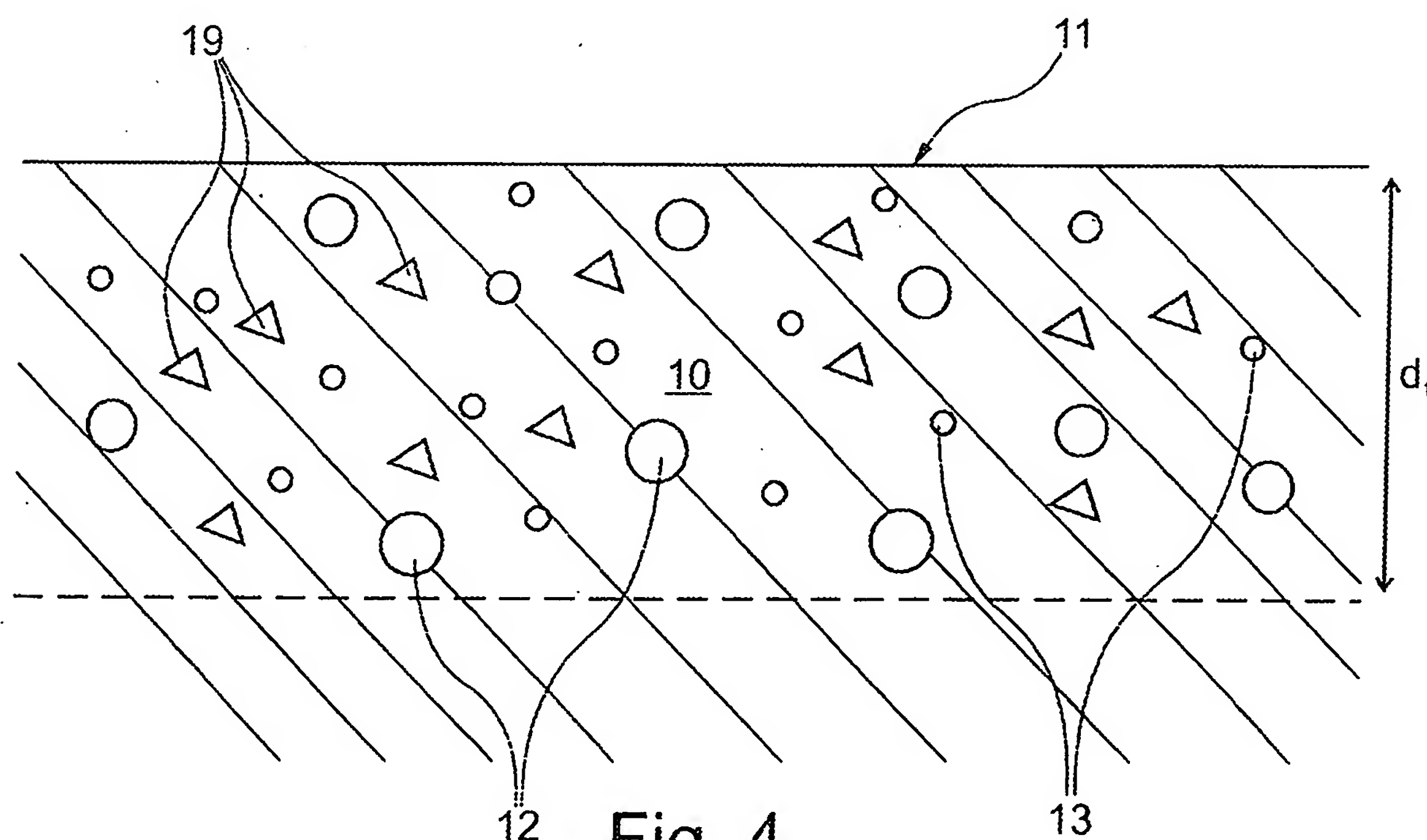


Fig. 4

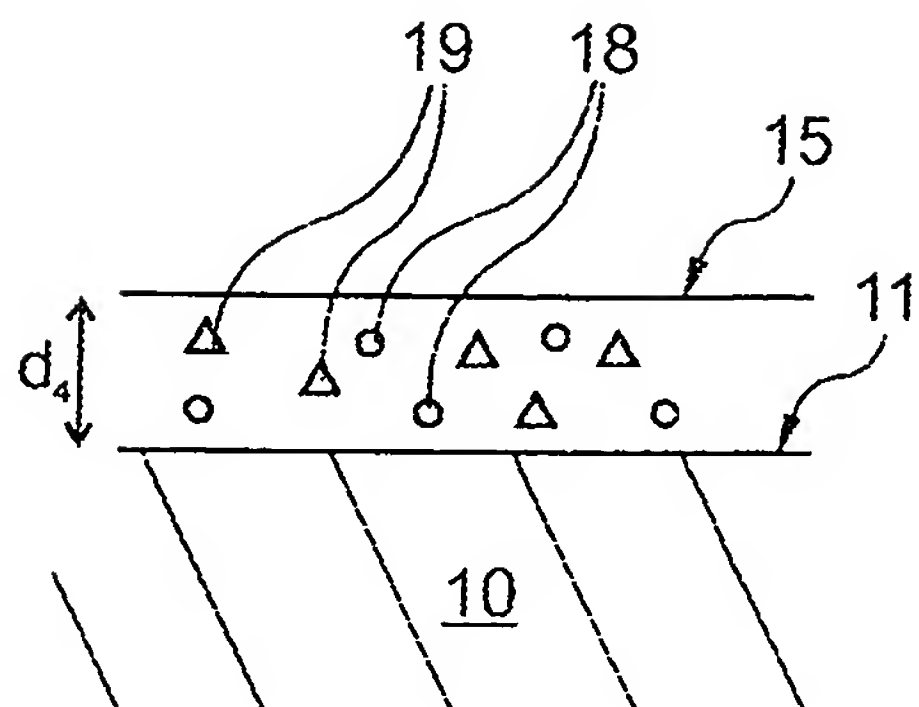


Fig. 5

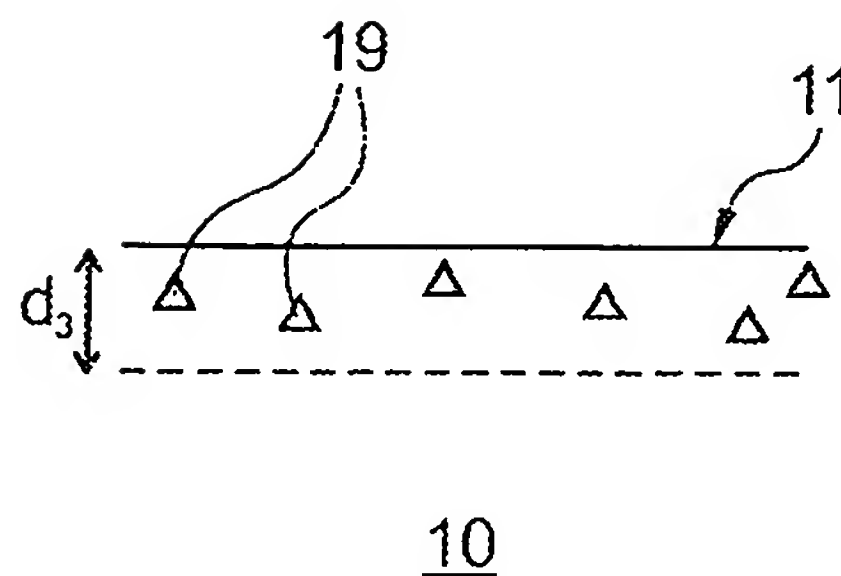


Fig. 8

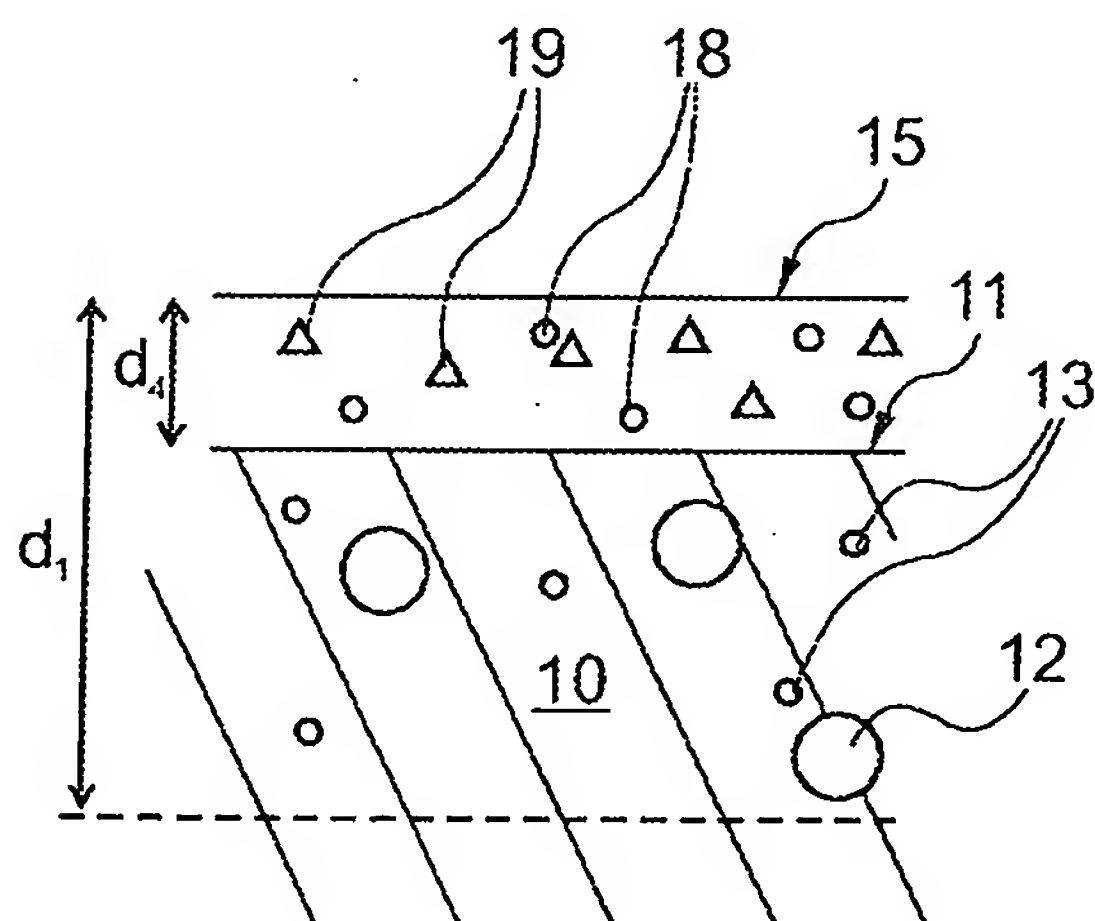


Fig. 6

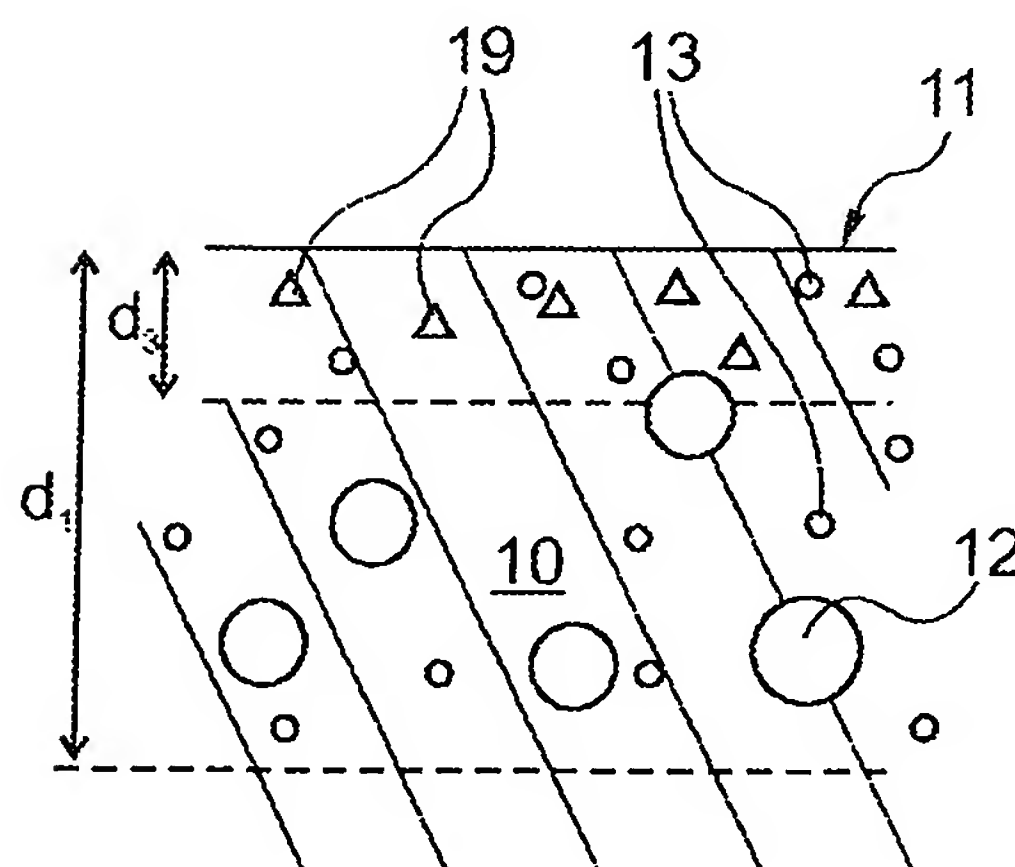


Fig. 9

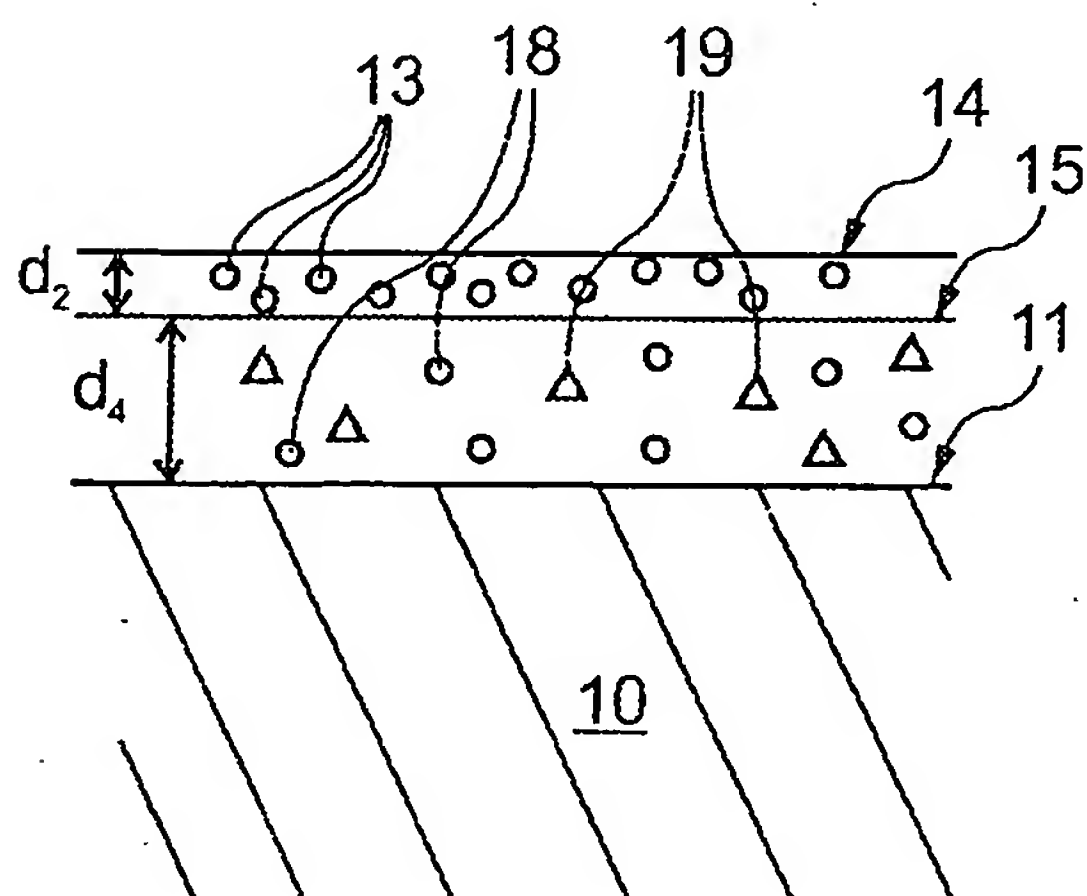


Fig. 7

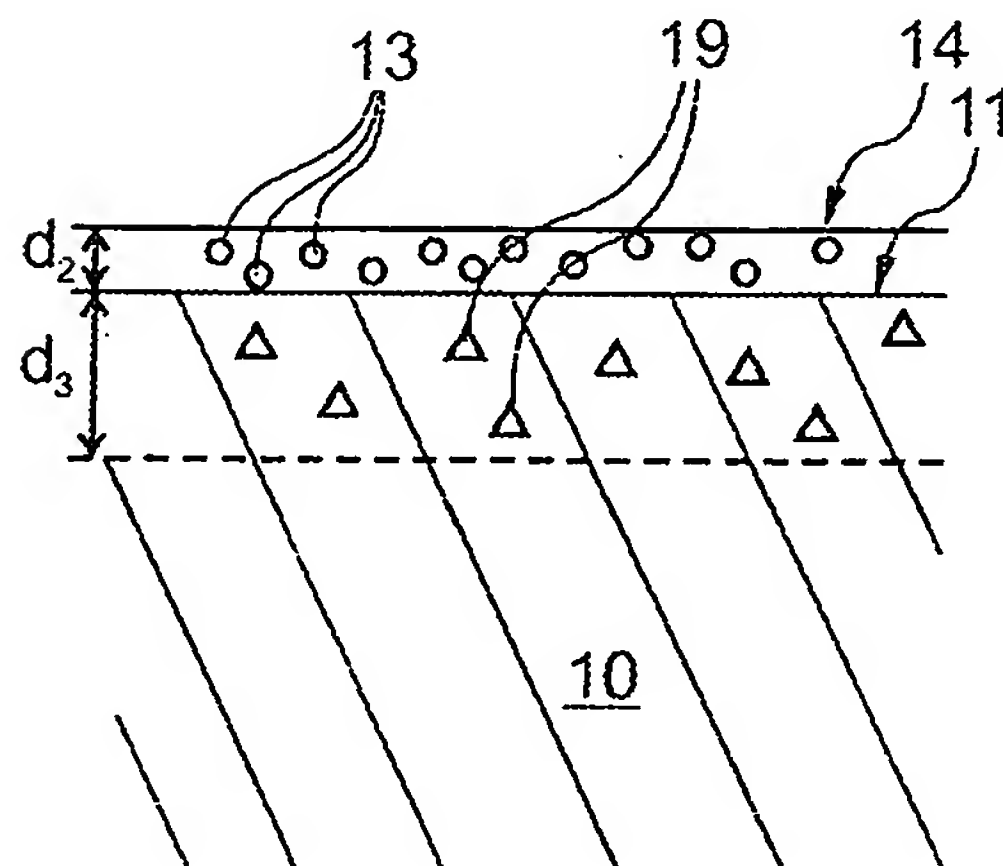


Fig. 10



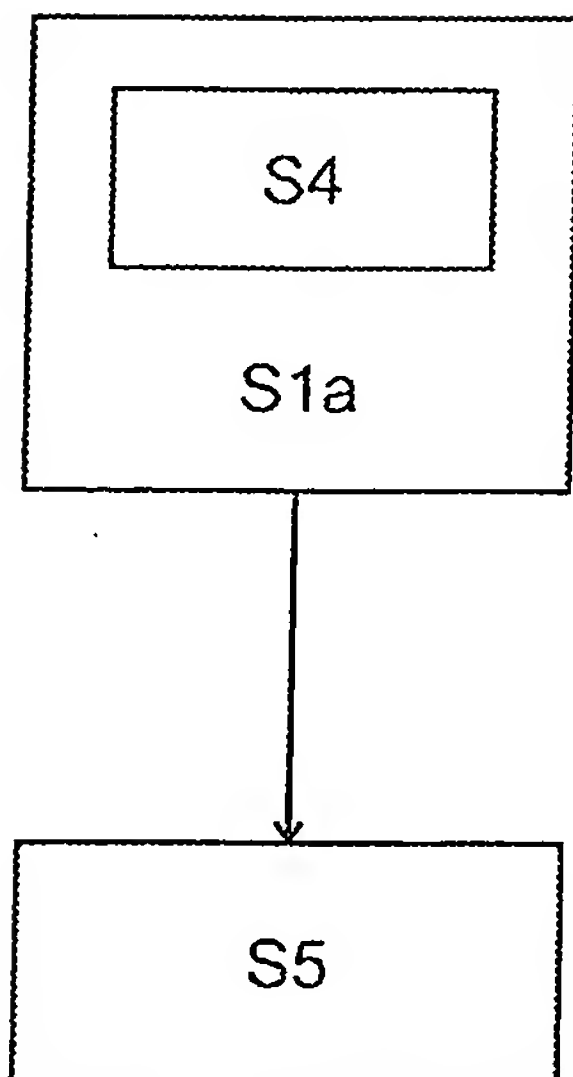


Fig. 11

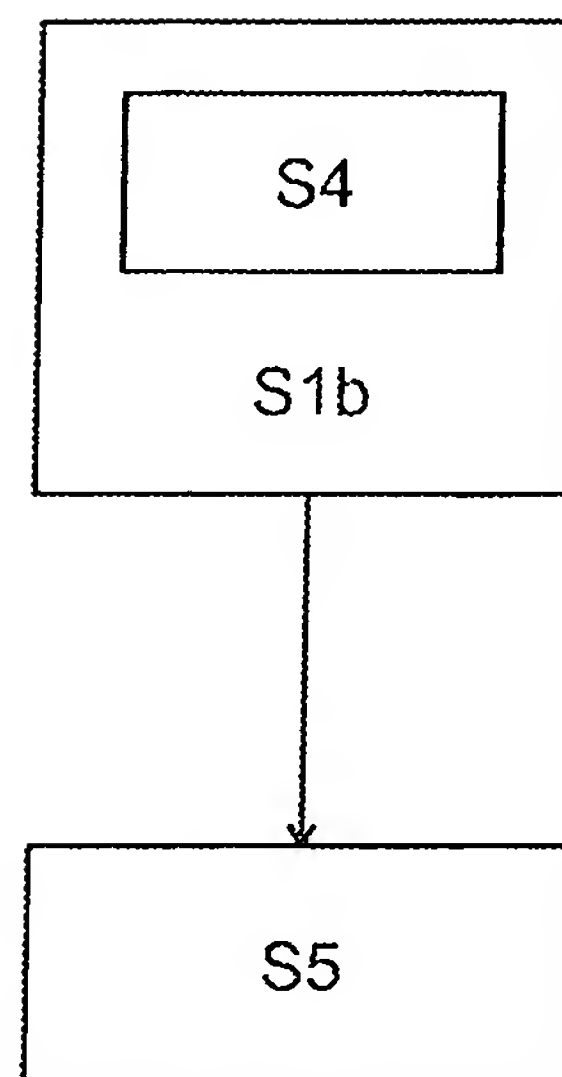


Fig. 12

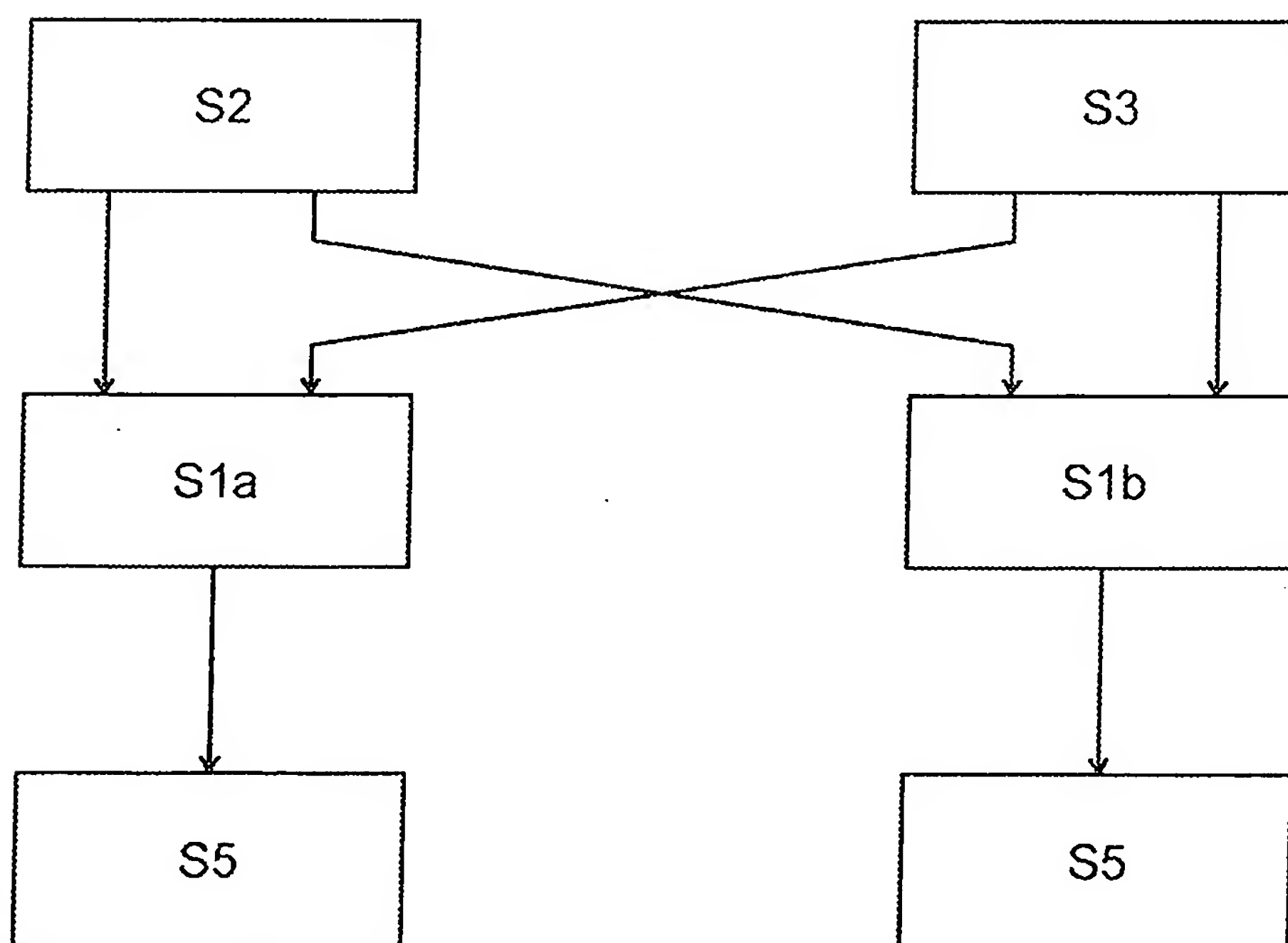


Fig. 13



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(BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR,  
NE, SN, TD, TG).

Published:

— with international search report (Art. 21(3))

— before the expiration of the time limit for amending the  
claims and to be republished in the event of receipt of  
amendments (Rule 48.2(h))

[Continued on next page]

(54) Title: ANTIMICROBIAL PROVISION OF TITANIUM AND TITANIUM ALLOYS WITH SILVER

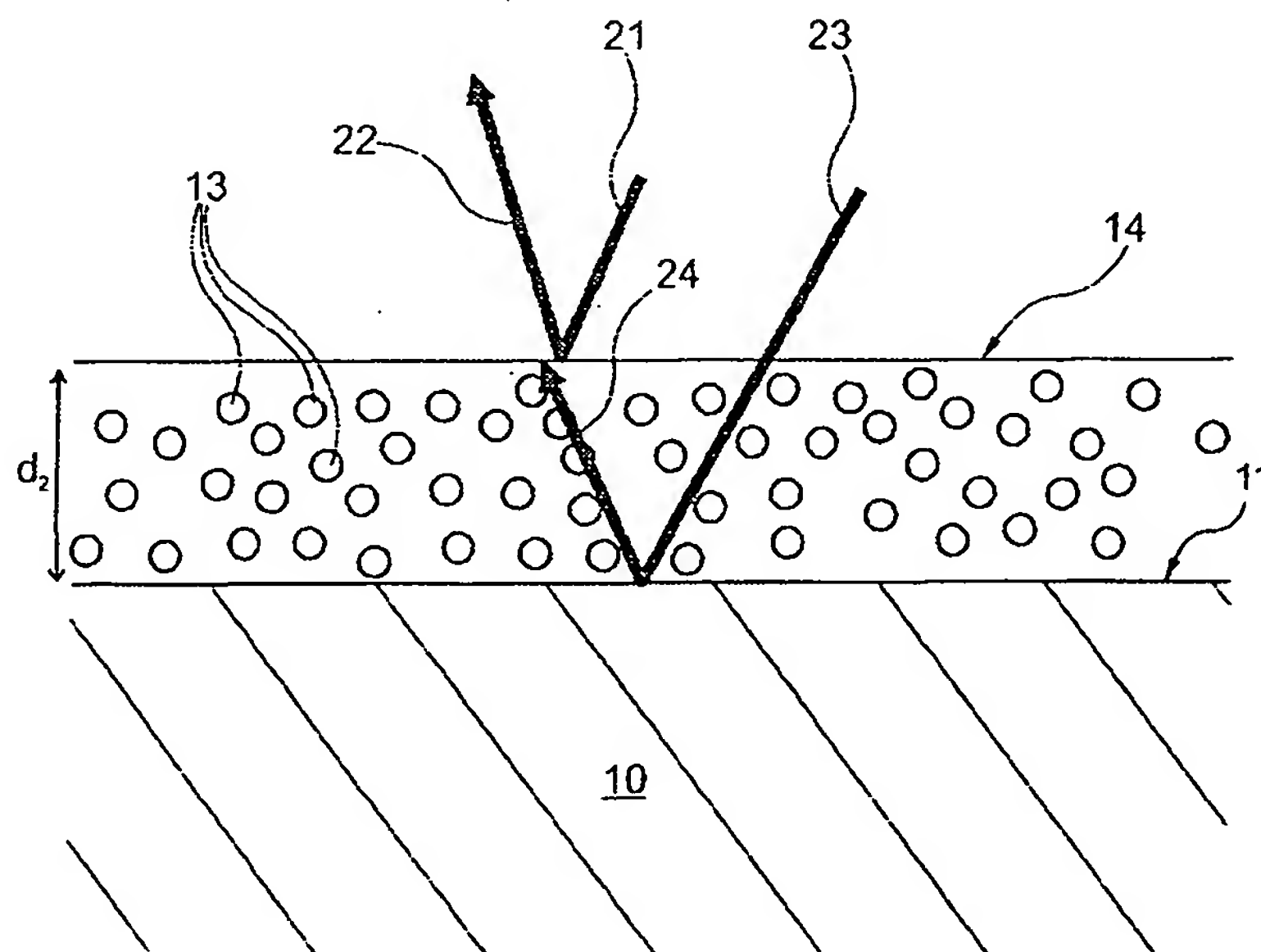


Fig. 1

(57) Abstract: A method for the antimicrobial provision of implant surfaces with silver, in which the method comprises an anodizing of the implant surface with an electrolyte, in which the electrolyte has a silver-yielding substance. Alternatively, the method comprises a silver implantation or a silver PVD deposition.



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## A. CLASSIFICATION OF SUBJECT MATTER

INV. C25D11/26 C23C14/16 C23C14/24 C23C14/48 A61K6/04  
A61L27/54

According to International Patent Classification (IPC) or to both national classification and IPC

## B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

C25D A61K A61L

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

EPO-Internal, WPI Data

## C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	US 2005/221259 A1 (ANDERSON DUNCAN M [GB]) 6 October 2005 (2005-10-06) paragraphs [0009] - [0012], [0017], [0032]	1-4, 7-8, 20-21
X	JP 2005 137801 A (SOKEN KK) 2 June 2005 (2005-06-02) paragraph [0033] - paragraph [0036] paragraphs [0043], [0048] figure 3	1-4, 7-8, 20-21
X	EP 1 207 220 A1 (SOUKEN CORP [JP] GHA CORP [JP]) 22 May 2002 (2002-05-22) paragraph [0029] paragraph [0061] - paragraph [0063]	1-4, 7-8, 20-21
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Further documents are listed in the continuation of Box C.



See patent family annex.

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C(Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	US 2007/181221 A1 (PICKFORD MARTIN E L [GB] ET AL) 9 August 2007 (2007-08-09) paragraphs [0014], [0015] -----	1-10
X	WAN ET AL: "Surface modification of medical metals by ion implantation of silver and copper" VACUUM, PERGAMON PRESS, GB, vol. 81, no. 9, 11 May 2007 (2007-05-11), pages 1114-1118, XP022070805 ISSN: 0042-207X the whole document -----	11,13, 20-21
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X	EWALD ANDREA ET AL: "Antimicrobial titanium/silver PVD coatings on titanium" BIOMEDICAL ENGINEERING ONLINE, BIOMED CENTRAL LTD, LONDON, GB, vol. 5, no. 1, 24 March 2006 (2006-03-24), page 22, XP021018047 ISSN: 1475-925X the whole document -----	14, 16-18, 20-21
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A	JUNG-YOON CHO, KYUNG-HO KIM, KWANG-CHUL CHOY, KEUN-TAEK OH, KYOUNG-NAM KIM: "Photocatalytic antibacterial effect of TiO2 film formed on Ti and TiAg exposed to Lactobacillus acidophilus" JOURNAL OF BIOMEDICAL MATERIALS RESEARCH PART B: APPLIED BIOMATERIALS, vol. 80B, no. 2, 18 July 2006 (2006-07-18), pages 353-359, XP002562873 the whole document -----	12,14,19
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C(Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	G. J. CHI ET AL: "Antibacterial activity of anodized aluminum with deposited silver" SURFACE AND COATINGS TECHNOLOGY, vol. 157, no. 2-3, 6 May 2002 (2002-05-06) , pages 162-165, XP002562874 the whole document -----	12,15,19
A	SHIRKHAZADEH M ET AL: "Bioactive delivery systems for the slow release of antibiotics: Incorporation of Ag<+> ions into micro-porous hydroxyapatite coatings" MATERIALS LETTERS, NORTH HOLLAND PUBLISHING COMPANY. AMSTERDAM, NL, vol. 24, no. 1-3, 1 June 1995 (1995-06-01) , pages 7-12, XP004067079 ISSN: 0167-577X the whole document -----	12,15,19

# INTERNATIONAL SEARCH REPORT

International application No.  
PCT/EP2008/066604

## Box No. II Observations where certain claims were found unsearchable (Continuation of item 2 of first sheet)

This international search report has not been established in respect of certain claims under Article 17(2)(a) for the following reasons:

1. ☐ Claims Nos.:  
because they relate to subject matter not required to be searched by this Authority, namely:
  
2. ☐ Claims Nos.:  
because they relate to parts of the international application that do not comply with the prescribed requirements to such an extent that no meaningful international search can be carried out, specifically:
  
3. ☐ Claims Nos.:  
because they are dependent claims and are not drafted in accordance with the second and third sentences of Rule 6.4(a).

## Box No. III Observations where unity of invention is lacking (Continuation of item 3 of first sheet)

This International Searching Authority found multiple inventions in this international application, as follows:

see additional sheet

1. ☒ As all required additional search fees were timely paid by the applicant, this international search report covers all searchable claims.
  
2. ☐ As all searchable claims could be searched without effort justifying an additional fees, this Authority did not invite payment of additional fees.
  
3. ☐ As only some of the required additional search fees were timely paid by the applicant, this international search report covers only those claims for which fees were paid, specifically claims Nos.:
  
4. ☐ No required additional search fees were timely paid by the applicant. Consequently, this international search report is restricted to the invention first mentioned in the claims; it is covered by claims Nos.:

### Remark on Protest

- ☐ The additional search fees were accompanied by the applicant's protest and, where applicable, the payment of a protest fee.
- ☐ The additional search fees were accompanied by the applicant's protest but the applicable protest fee was not paid within the time limit specified in the invitation.
- ☒ No protest accompanied the payment of additional search fees.



FURTHER INFORMATION CONTINUED FROM PCT/ISA/ 210

This International Searching Authority found multiple (groups of) inventions in this international application, as follows:

1. claims: 1-10(completely); 20-21(partially)

A method for the antimicrobial provision of implant with silver, comprising an anodizing step.  
---

2. claims: 11-13(completely); 20-21(partially)

A method for the antimicrobial provision of implant with silver, comprising a silver implantation.  
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3. claims: 14-19(completely); 20-21(partially)

A method for the antimicrobial provision of implant with silver, comprising a physical gas phase deposition.  
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